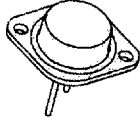


# NEW ENGLAND SEMICONDUCTOR

## BIPOLAR PNP TRANSISTOR TO-3

PACKAGE	DEVICE TYPE	V <sub>CEO</sub> (sus) VOLTS	I <sub>C</sub> (max) AMPS	h <sub>FE</sub> @ I <sub>C</sub> /V <sub>CE</sub> (min/max @ A/V)	V <sub>CE(sat)</sub> @ I <sub>C</sub> /I <sub>B</sub> (V @ A/A)	P <sub>D</sub> * WATTS	f <sub>T</sub> (MHz)
PNP TO-3  	2N3789	60	10	25-90@1/2	1@4/4	150	4
	2N3790	80	10	25-90@1/2	1@4/4	150	4
	2N3791^	60	10	50-150@1/2	1@5/5	150	4
	2N3792^	80	10	50-150@1/2	1@5/5	150	4
	2N4398	40	30	15-60@15/2	2@20/2	200	4
	2N4399^	60	30	15-60@15/2	2@20/2	200	4
	2N4901	40	5	20-80@1/2	1.5@5/1	87.5	4
	2N4902	60	5	20-80@1/2	1.5@5/1	87.5	4
	2N4903	80	5	20-80@1/2	1.5@5/1	87.5	4
	2N5683^	60	50	15-60@25/2	1@25/2.5	300	2
	2N5684^	80	50	15-60@25/2	1@25/2.5	300	2
	2N5745^	80	20	15-60@10/2	2@20/4	200	2
	2N5875	60	10	20-100@4/4	1@5/5	150	4
	2N5876	80	10	20-100@4/4	1@5/5	150	4
	2N5879	60	15	20-100@6/4	1@7/7	160	4
	2N5880	80	15	20-100@6/4	1@7/7	160	4
	2N5883	60	25	20-100@10/4	1@15/1.5	200	4
	2N5884	80	25	20-100@10/4	1@15/1.5	200	4
	2N6246	60	15	20-100@7/4	1.3@7/7	125	6
	2N6247	80	15	20-100@6/4	1.3@6/6	125	6
	2N6329	60	30	6-30@30/4	1.5@15/2	200	3
2N6330	80	30	6-30@30/4	1.5@15/2	200	3	
2N6331	100	30	6-30@30/4	1.5@15/2	200	3	

\* T<sub>C</sub> = 25°C

^Available in JAN, JANTX, JANTXV